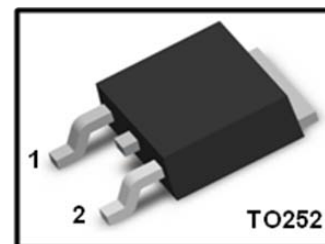


PRODUCT FEATURES

- Ultrafast Recovery Time
- Soft Recovery Characteristics
- Low Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Leakage Current

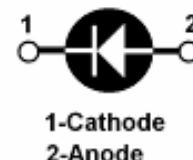
APPLICATIONS

- Freewheeling, Snubber, Clamp
- Inversion Welder
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper, PFC
- UPS



DESCRIPTION

FRED from MacMic utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.



ABSOLUTE MAXIMUM RATINGS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V_R	Maximum D.C. Reverse Voltage		600	V
V_{RRM}	Maximum Repetitive Reverse Voltage		600	V
$I_{F(AV)}$	Average Forward Current	$T_C=110^{\circ}\text{C}$, Per Diode	8	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=110^{\circ}\text{C}$, Per Diode	11	A
I_{FSM}	Non-Repetitive Surge Forward Current	$T_J=45^{\circ}\text{C}$, $t=10\text{ms}$, 50Hz, Sine	100	A
P_D	Power Dissipation		50	W
T_J	Junction Temperature		-55 to +150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range		-55 to +150	$^{\circ}\text{C}$
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case, Per Diode	2.5	$^{\circ}\text{C}/\text{W}$
Weight			2.5	g

ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R=600\text{V}$	--	--	10	μA
		$V_R=600\text{V}$, $T_J=125^{\circ}\text{C}$	--	--	10	mA
V_F	Forward Voltage	$I_F=8\text{A}$	--	1.5	2.2	V
		$I_F=8\text{A}$, $T_J=125^{\circ}\text{C}$	--	1.25	--	V
t_{rr}	Reverse Recovery Time	$I_F=1\text{A}$, $V_R=30\text{V}$, $di_F/dt=-200\text{A}/\mu\text{s}$	--	19	--	ns
t_{rr}	Reverse Recovery Time	$V_R=300\text{V}$, $I_F=8\text{A}$ $di_F/dt=-200\text{A}/\mu\text{s}$, $T_J=25^{\circ}\text{C}$	--	35	--	ns
I_{RRM}	Max. Reverse Recovery Current		--	3	--	A
t_{rr}	Reverse Recovery Time	$V_R=300\text{V}$, $I_F=8\text{A}$ $di_F/dt=-200\text{A}/\mu\text{s}$, $T_J=125^{\circ}\text{C}$	--	110	--	ns
I_{RRM}	Max. Reverse Recovery Current		--	4.5	--	A
S			--	3	--	--

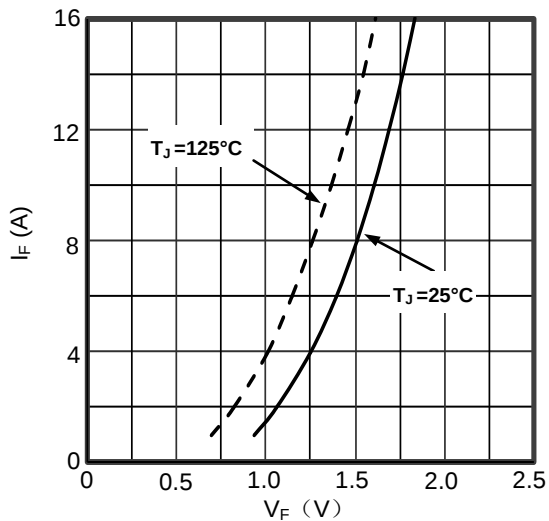


Fig1. Forward Voltage Drop vs Forward Current

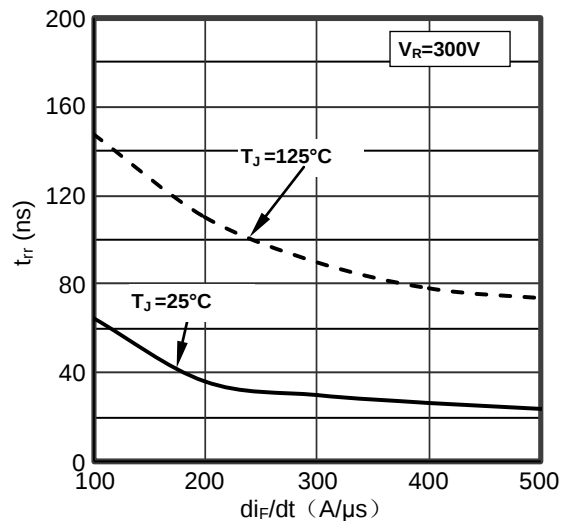


Fig2. Reverse Recovery Time vs di_F/dt

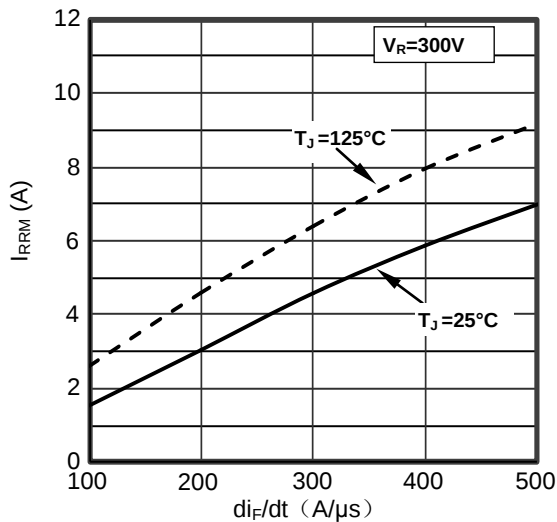


Fig3. Reverse Recovery Current vs di_F/dt

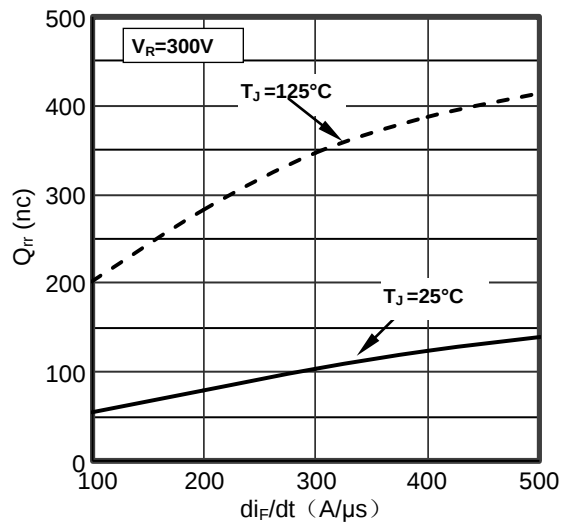


Fig4. Reverse Recovery Charge vs di_F/dt

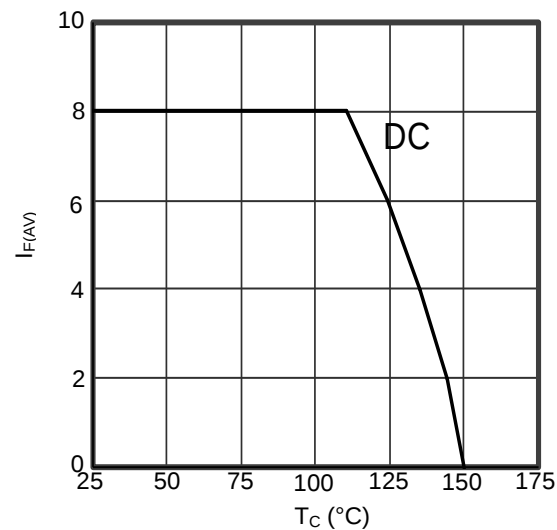


Fig5. Forward current vs. Case temperature

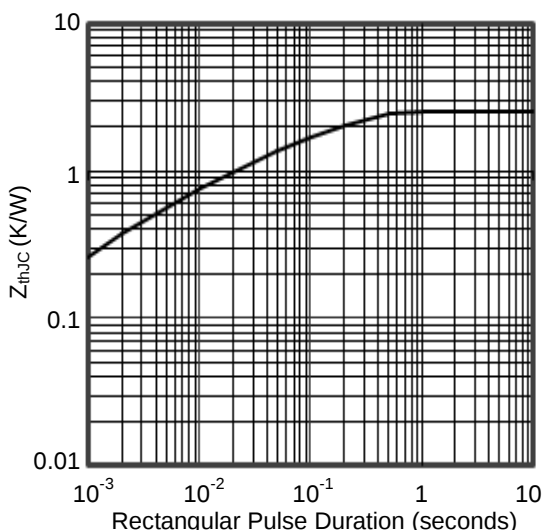


Fig6. Transient Thermal Impedance

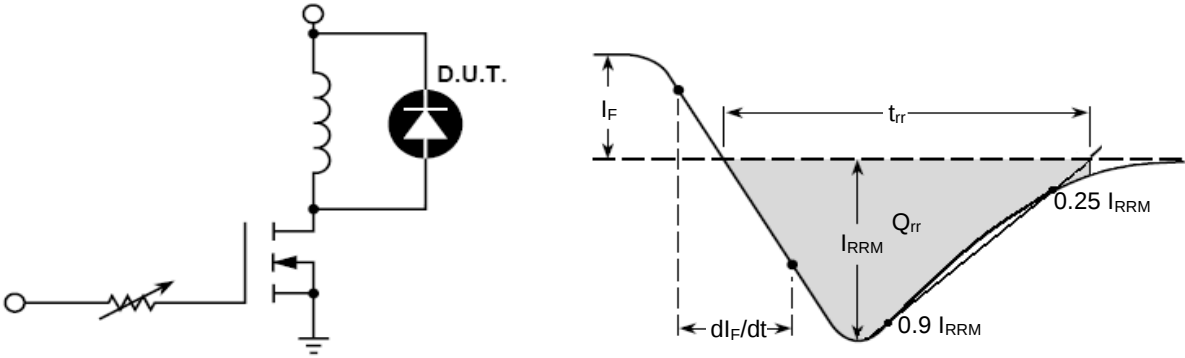
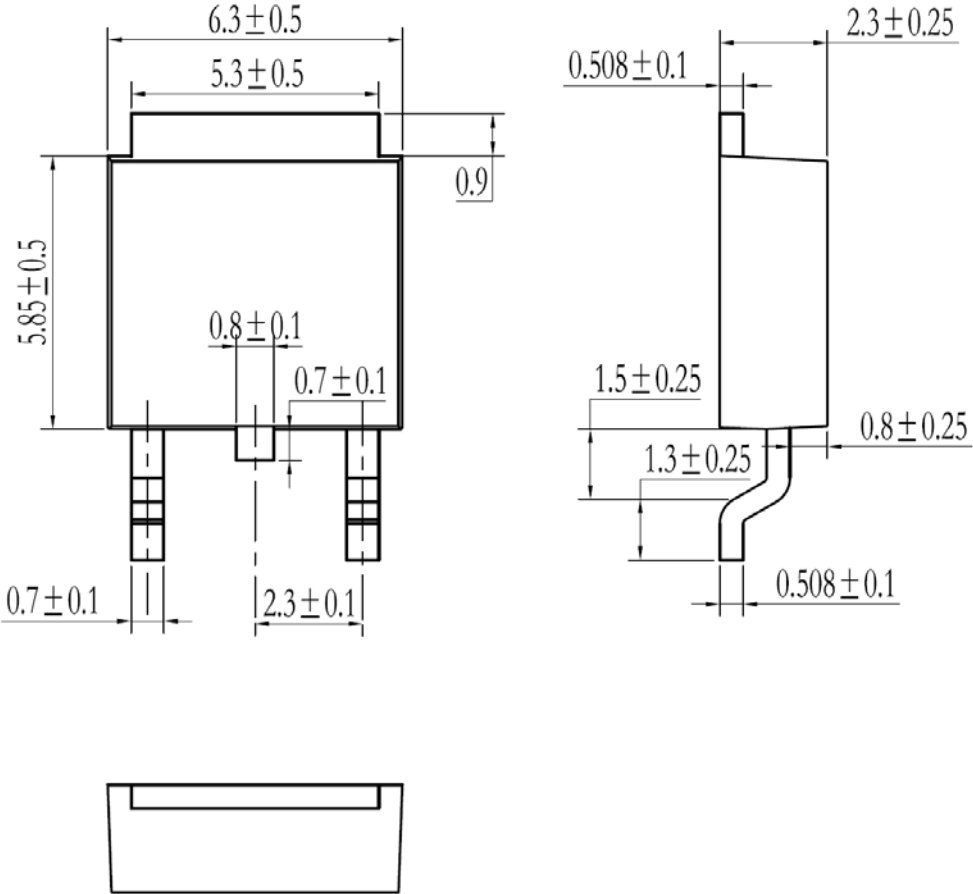


Fig7. Diode Reverse Recovery Test Circuit and Waveform



Dimensions in Millimeters
Fig8. Package Outline